



LM833

Low Noise Dual Operational Amplifier

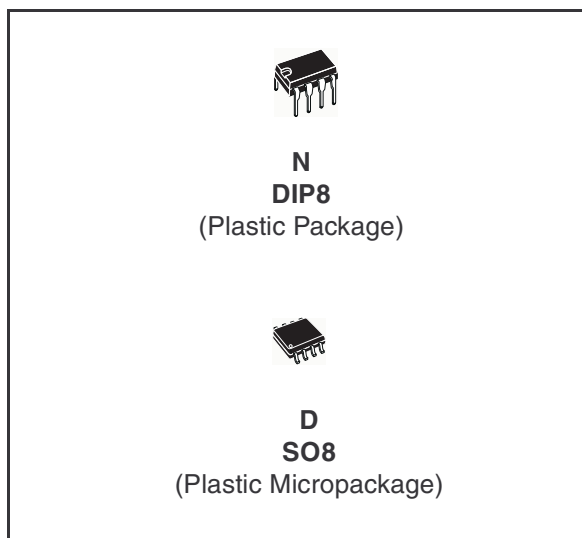
- Low voltage noise: **4.5nV/√Hz**
- High gain bandwidth product: **15MHz**
- High slew rate: **7V/μs**
- Low distortion: 0.002%
- Excellent frequency stability
- ESD protection 2kV

Description

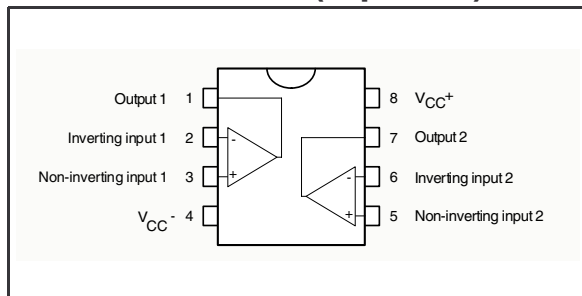
The LM833 is a monolithic dual operational amplifier particularly well suited for audio applications.

It offers low voltage noise (4.5nV/√Hz) and high frequency performances (15MHz Gain Bandwidth product, 7V/μs slew rate).

In addition the LM833 has also a very low distortion (0.002%) and excellent phase/gain margins.



Pin Connections (top view)



Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
LM833N	-40, +105°C	DIP8	Tube	LM833N
LM833D/DT		S8-8	Tube or Tape & Reel	833
LM833YD/YDT	-40, +125°C	SO-8 (automotive grade level)	Tube or Tape & Reel	833Y

1 Absolute Maximum Ratings

Table 1. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 18 or $+36$	V
V_{id}	Differential Input Voltage - note ⁽¹⁾	± 30	V
V_i	Input Voltage - see note 1	± 15	V
	Output Short Circuit Duration	Infinite	s
T_{oper}	Operating Free-Air Temperature Range	-40 to 105	°C
T_j	Junction Temperature	+150	°C
T_{stg}	Storage Temperature	-65 to +150	°C
P_{tot}	Maximum Power Dissipation - note ⁽²⁾	500	mW
ESD	HBM: Human Body Model ⁽³⁾	2	kV
	MM: Machine Model ⁽⁴⁾	200	V
	CDM: Charged Device Model	1500	V

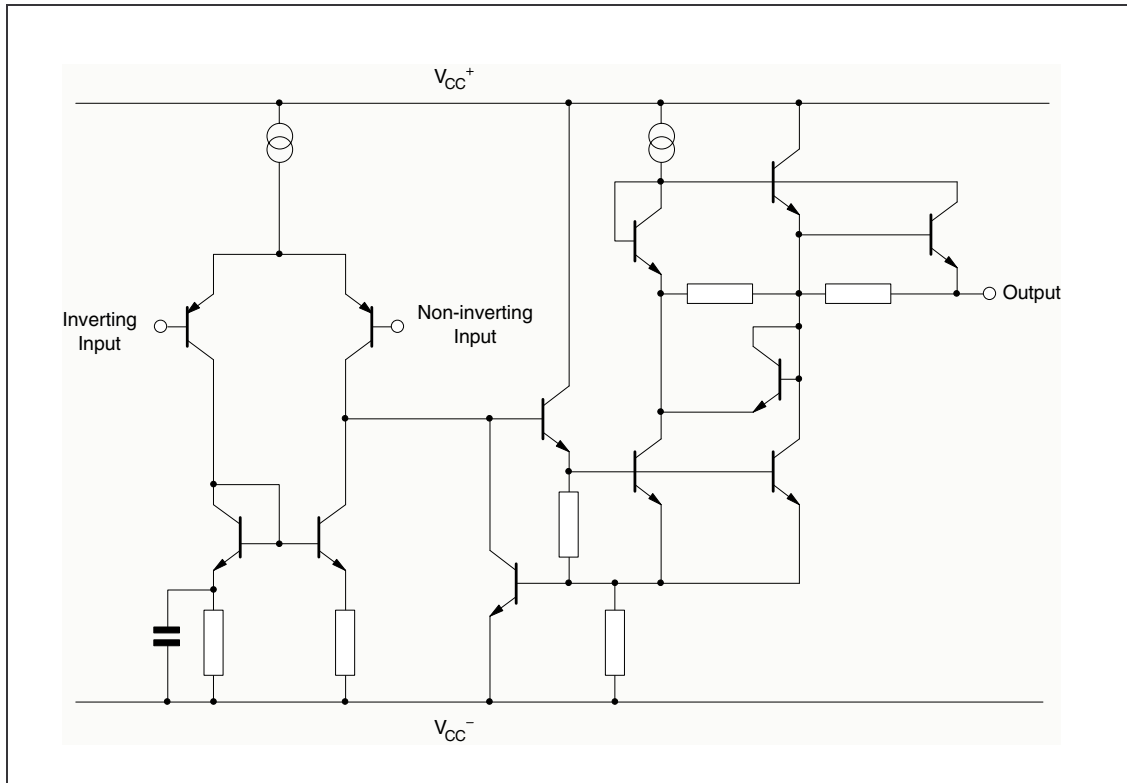
1. Either or both input voltages must not exceed the magnitude of V_{CC}^+ or V_{CC}^- .
2. Power dissipation must be considered to ensure maximum junction temperature (T_j) is not exceeded.
3. Human body model, 100pF discharged through a 1.5k Ω resistor into pin of device.
4. Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5 Ω), into pin to pin of device.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	± 2.5 to ± 15	V

2 Typical Application Schematics

Figure 1. Schematic diagram (1/2 LM833)



3 Electrical Characteristics

Table 3. $V_{CC}^+ = +15V$, $V_{CC}^- = -15V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ($R_s = 10\Omega$, $V_o = 0V$, $V_{ic} = 0V$)		0.3	5	mV
DV_{io}	Input Offset Voltage Drift $R_s = 10\Omega$, $V_o = 0V$, $T_{min} \leq T_{amb} \leq T_{max}$.		2		$\mu V/^\circ C$
I_{io}	Input Offset Current ($V_o = 0V$, $V_{ic} = 0V$)		25	200	nA
I_{ib}	Input Bias Current ($V_o = 0V$, $V_{ic} = 0V$)		300	1000	nA
V_{icm}	Input Common Mode Voltage Range	± 12	± 14		V
A_{vd}	Large Signal Voltage Gain ($R_L = 2k\Omega$, $V_o = \pm 10V$)	90	100		dB
$\pm V_{opp}$	Output Voltage Swing ($V_{id} = \pm 1V$) $R_L = 2.0k\Omega$ $R_L = 2.0k\Omega$ $R_L = 10k\Omega$ $R_L = 10k\Omega$	10 12	13.7 -14 13.9 -14.4	-10 -12	V
CMR	Common-mode Rejection Ratio ($V_{ic} = \pm 13V$)	80	100		dB
SVR	Supply Voltage Rejection Ratio ($V_{CC}^+ / V_{CC}^- = +15V / -15V$ to $+5V / -5V$)	80	105		dB
I_{CC}	Supply Current ($V_o = 0V$, All amplifiers)		4	8	mA
SR	Slew Rate ($V_i = -10V$ to $+10V$, $R_L = 2k\Omega$, $A_V = +1$)	5	7		V/ μs
GBP	Gain Bandwidth Product ($R_L = 2k\Omega$, $C_L = 100pF$, $f = 100kHz$)	10	15		MHz
B	Unity Gain Bandwidth (Open loop)		9		MHz
ϕ_m	Phase Margin ($R_L = 2k\Omega$)		60		Degrees
e_n	Equivalent Input Noise Voltage ($R_s = 100\Omega$, $f = 1kHz$)		4.5		$\frac{nV}{\sqrt{Hz}}$
i_n	Equivalent Input Noise Current ($f = 1kHz$)		0.5		$\frac{pA}{\sqrt{Hz}}$
THD	Total Harmonic Distortion ($R_L = 2k\Omega$, $f = 20Hz$ to $20kHz$, $V_o = 3V_{rms}$, $A_V = +1$)		0.002		%
V_{O1}/V_{O2}	Channel Separation ($f = 20Hz$ to $20kHz$)		120		dB
FPB	Full Power Bandwidth ($V_o = 27V_{pp}$, $R_L = 2k\Omega$, $THD \leq 1\%$)		120		kHz

Figure 2. Total supply current vs. supply voltage

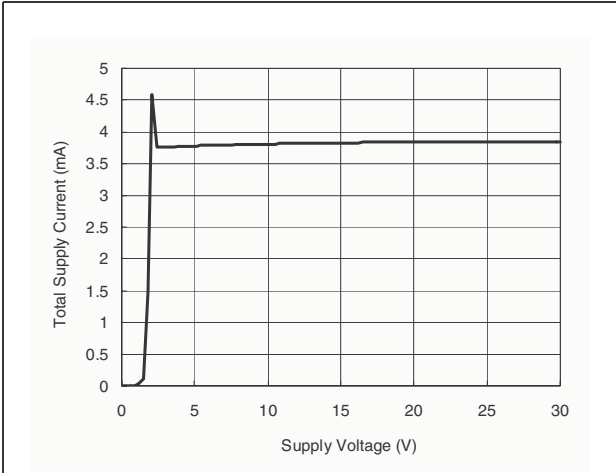


Figure 3. Output voltage vs. supply voltage

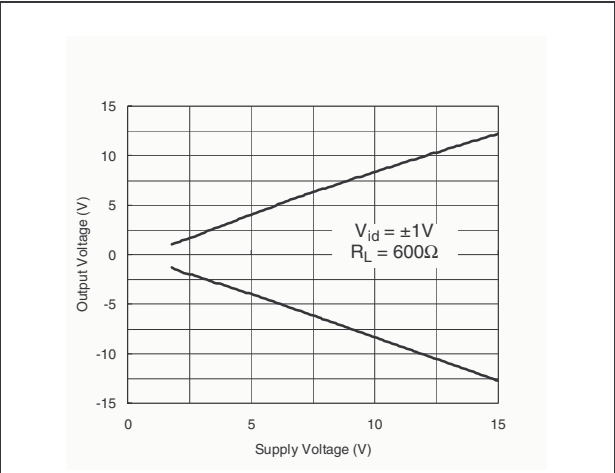


Figure 4. Equivalent input noise voltage vs. frequency

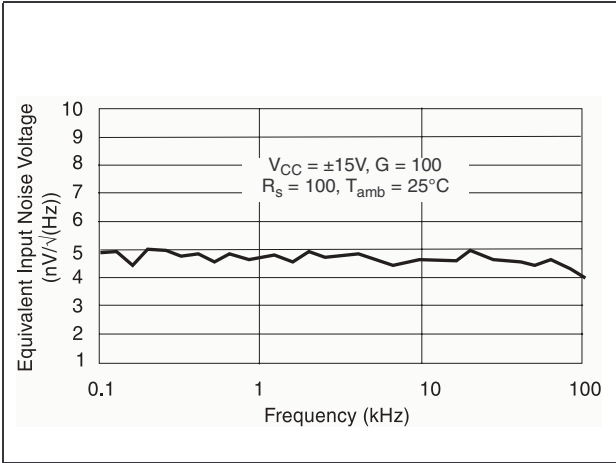


Figure 5. Output short circuit current vs. output voltage

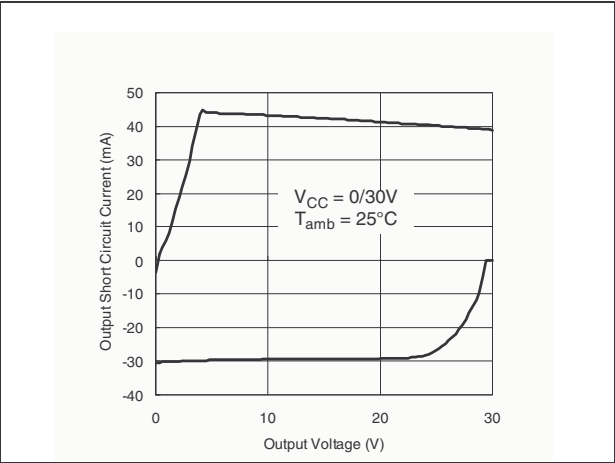


Figure 6. Output voltage vs. supply voltage

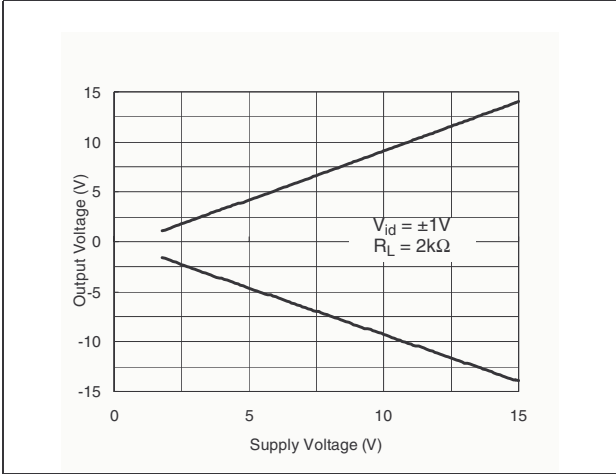


Figure 7. THD+ noise vs. frequency

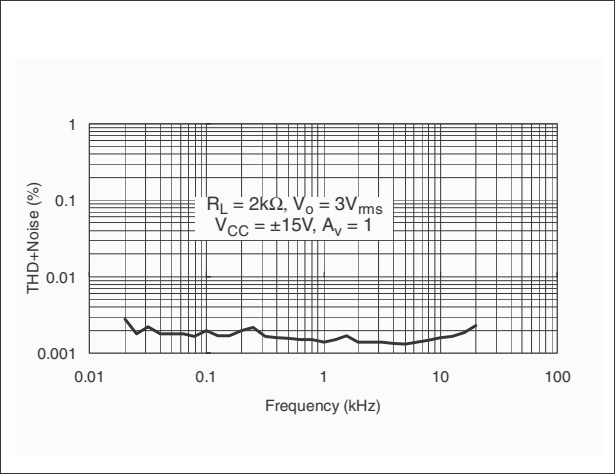


Figure 8. Voltage gain and phase vs. frequency

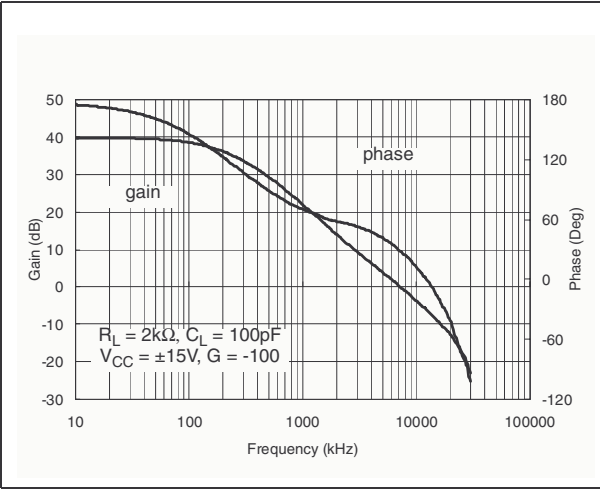
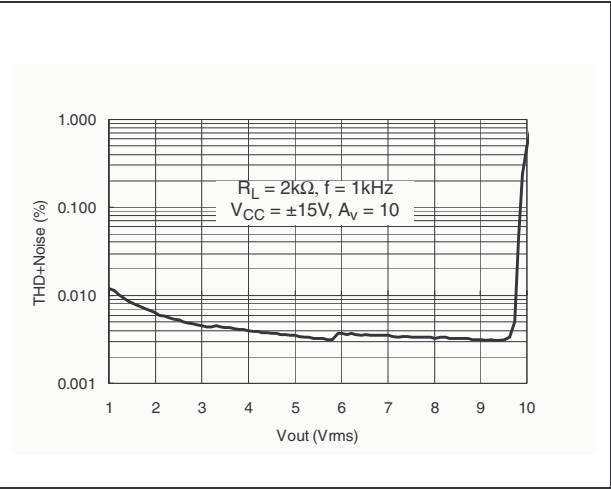


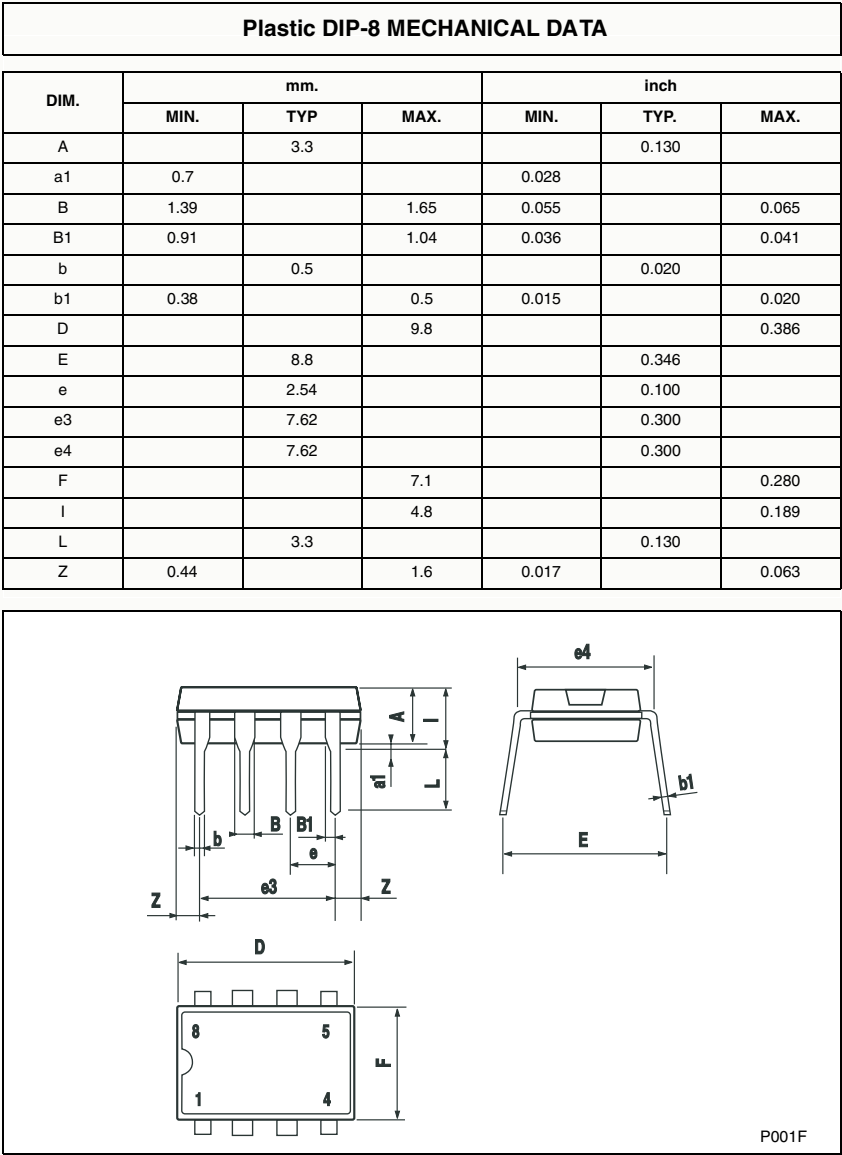
Figure 9. THD + noise vs. V_{out}



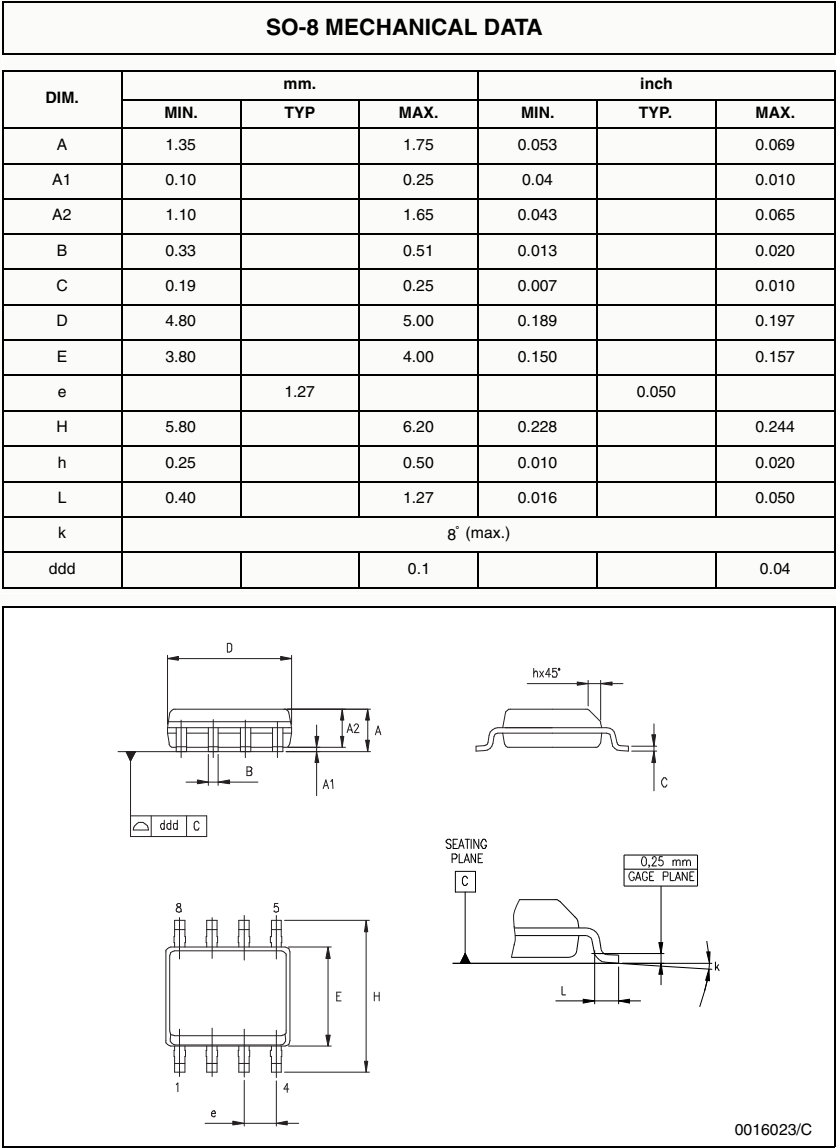
4 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4.1 DIP-8 Package



4.2 SO-8 Package



5 Revision History

Date	Revision	Changes
Nov. 2001	1	Initial release.
July 2005	2	1 - PPAP references inserted in the datasheet see <i>Table on page 1</i> . 2 - ESD protection inserted in <i>Table 1 on page 2</i>

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